



SANYO Semiconductors

# DATA SHEET

An ON Semiconductor Company

## EMH2407 — N-Channel Silicon MOSFETs General-Purpose Switching Device Applications

### Features

- Low ON-resistance
- Best suited for LiB charging and discharging switch
- Common-drain type
- 2.5V drive
- Protection diode in

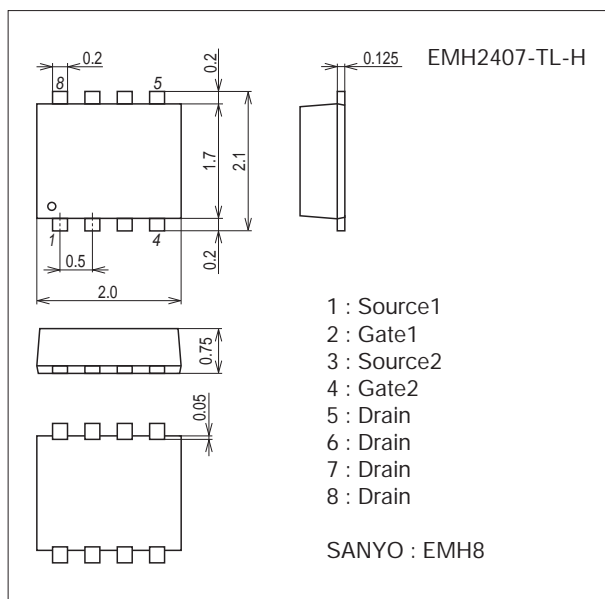
### Specifications

Absolute Maximum Ratings at Ta=25°C

Parameter	Symbol	Conditions	Ratings	Unit
Drain-to-Source Voltage	V <sub>DSS</sub>		20	V
Gate-to-Source Voltage	V <sub>GSS</sub>		±12	V
Drain Current (DC)	I <sub>D</sub>		6	A
Drain Current (Pulse)	I <sub>DP</sub>	PW≤10μs, duty cycle≤1%	40	A
Allowable Power Dissipation	P <sub>D</sub>	When mounted on ceramic substrate (900mm <sup>2</sup> ×0.8mm) 1unit	1.3	W
Total Dissipation	P <sub>T</sub>	When mounted on ceramic substrate (900mm <sup>2</sup> ×0.8mm)	1.4	W
Channel Temperature	T <sub>ch</sub>		150	°C
Storage Temperature	T <sub>stg</sub>		-55 to +150	°C

### Package Dimensions

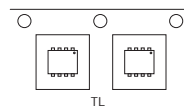
unit : mm (typ)  
7045-006



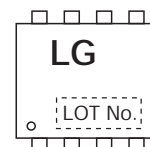
### Product & Package Information

- Package : EMH8
- JEITA, JEDEC :-
- Minimum Packing Quantity : 3,000 pcs./reel

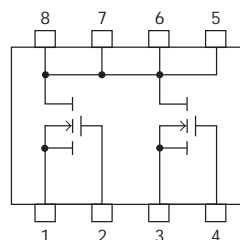
Packing Type : TL



Marking



### Electrical Connection



SANYO Semiconductor Co., Ltd.

<http://www.sanyosemi.com/en/network/>

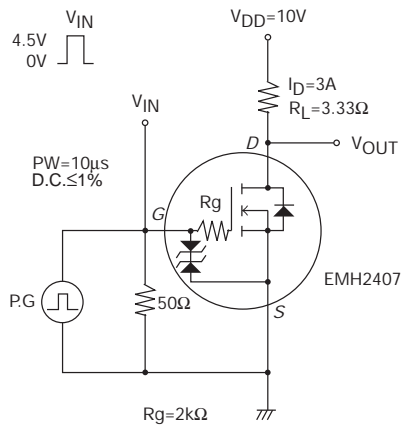
91212 TKIM/51612 TKIM/90308 TIIM/80608 TIIM/31908PE TIIM TC-00001276 No. A1141-1/7

# EMH2407

## Electrical Characteristics at $T_a=25^\circ\text{C}$

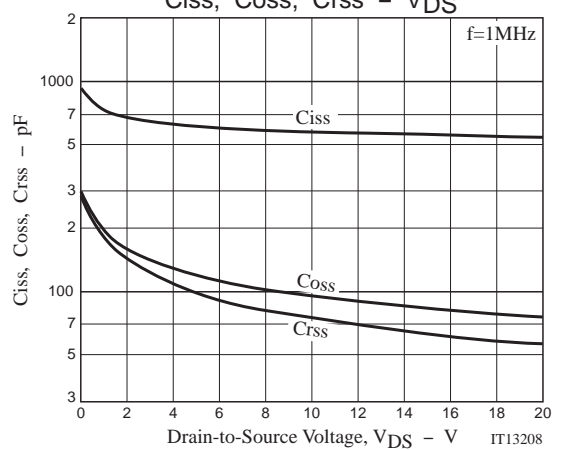
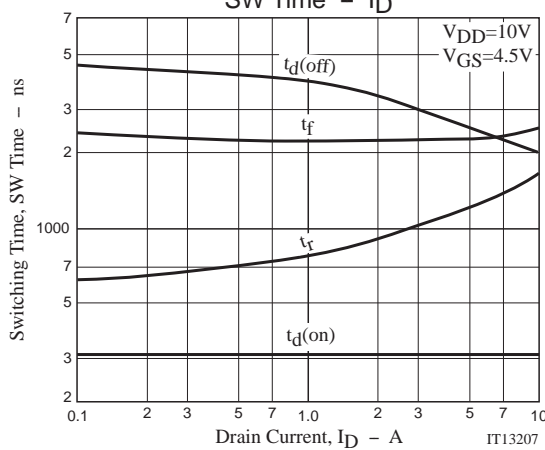
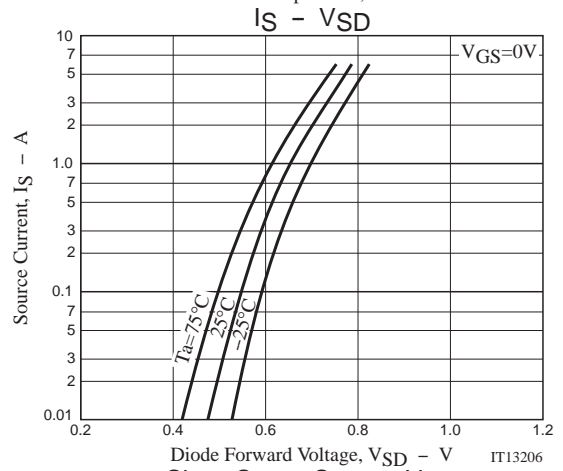
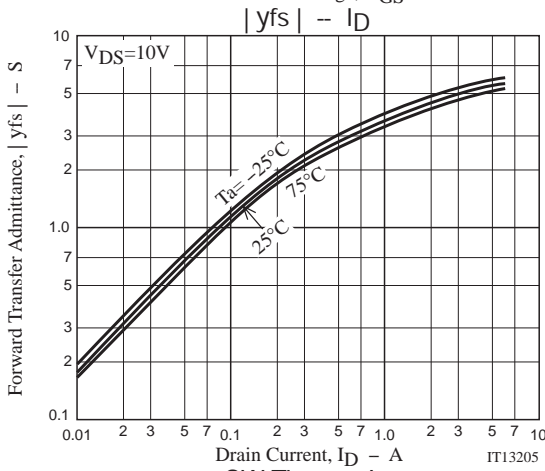
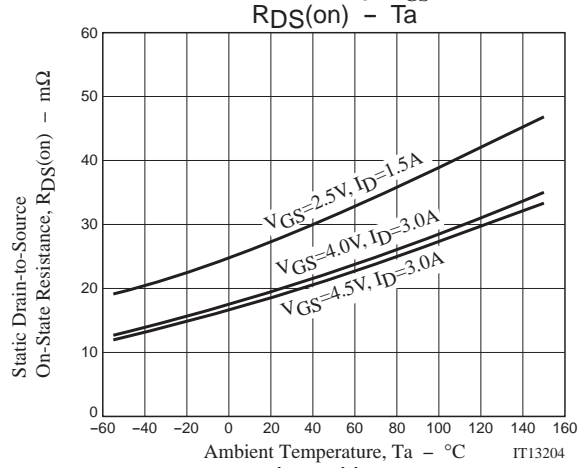
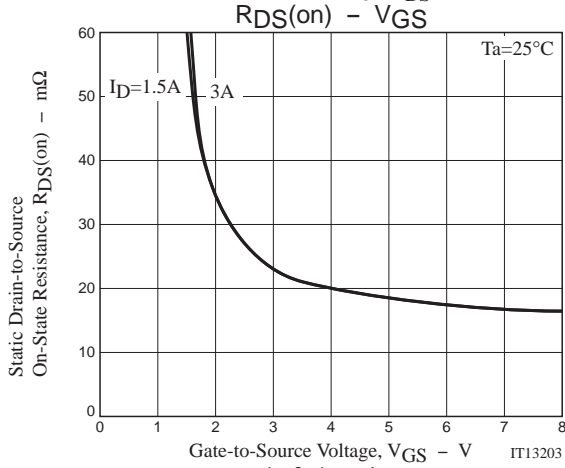
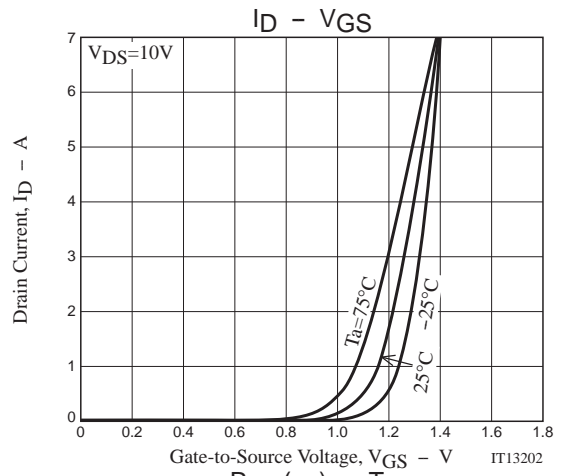
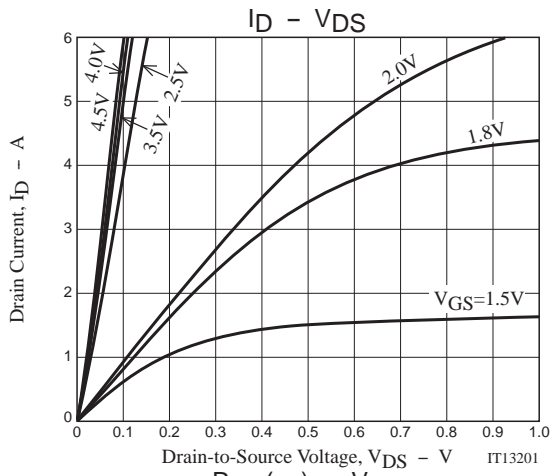
Parameter	Symbol	Conditions	Ratings			Unit
			min	typ	max	
Drain-to-Source Breakdown Voltage	$V_{(BR)DSS}$	$I_D=1\text{mA}, V_{GS}=0\text{V}$	20			V
Zero-Gate Voltage Drain Current	$I_{DSS}$	$V_{DS}=20\text{V}, V_{GS}=0\text{V}$			1	$\mu\text{A}$
Gate-to-Source Leakage Current	$I_{GSS}$	$V_{GS}=\pm 8\text{V}, V_{DS}=0\text{V}$			$\pm 10$	$\mu\text{A}$
Cutoff Voltage	$V_{GS(off)}$	$V_{DS}=10\text{V}, I_D=1\text{mA}$	0.5		1.3	V
Forward Transfer Admittance	$ y_{fs} $	$V_{DS}=10\text{V}, I_D=3\text{A}$	3	5		S
Static Drain-to-Source On-State Resistance	$R_{DS(on)1}$	$I_D=3\text{A}, V_{GS}=4.5\text{V}$	13	19	25	$\text{m}\Omega$
	$R_{DS(on)2}$	$I_D=3\text{A}, V_{GS}=4\text{V}$	14	20	26	$\text{m}\Omega$
	$R_{DS(on)3}$	$I_D=1.5\text{A}, V_{GS}=2.5\text{V}$	16	28	39	$\text{m}\Omega$
Input Capacitance	$C_{iss}$	$V_{DS}=10\text{V}, f=1\text{MHz}$		580		pF
Output Capacitance	$C_{oss}$			95		pF
Reverse Transfer Capacitance	$C_{rss}$			75		pF
Turn-ON Delay Time	$t_d(on)$		See specified Test Circuit.		310	
Rise Time	$t_r$			1020		ns
Turn-OFF Delay Time	$t_d(off)$			3000		ns
Fall Time	$t_f$			2250		ns
Total Gate Charge	$Q_g$	$V_{DS}=10\text{V}, V_{GS}=4.5\text{V}, I_D=6\text{A}$			6.3	
Gate-to-Source Charge	$Q_{gs}$			0.83		nC
Gate-to-Drain "Miller" Charge	$Q_{gd}$			1.9		nC
Diode Forward Voltage	$V_{SD}$	$I_S=6\text{A}, V_{GS}=0\text{V}$		0.78	1.2	V

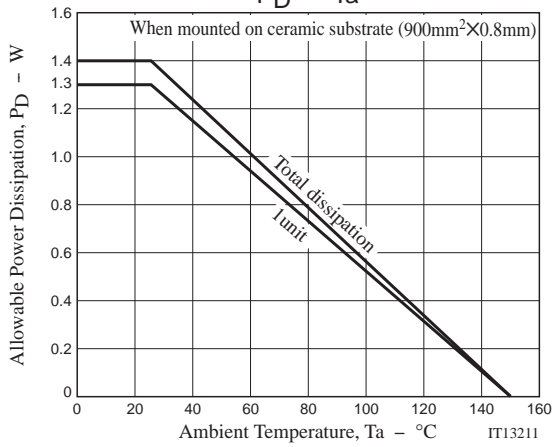
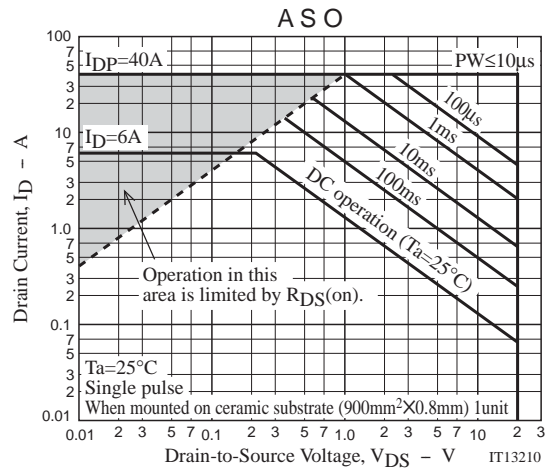
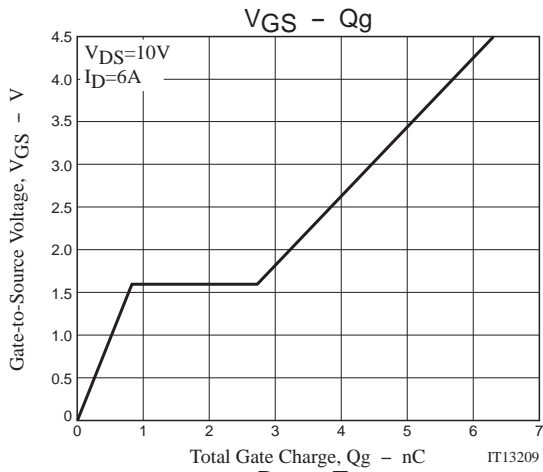
## Switching Time Test Circuit



## Ordering Information

Device	Package	Shipping	memo
EMH2407-TL-H	EMH8	3,000pcs./reel	Pb Free and Halogen Free



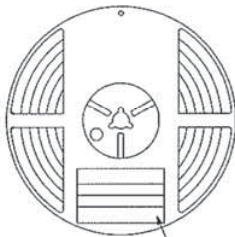


Embossed Taping Specification  
EMH2407-TL-H

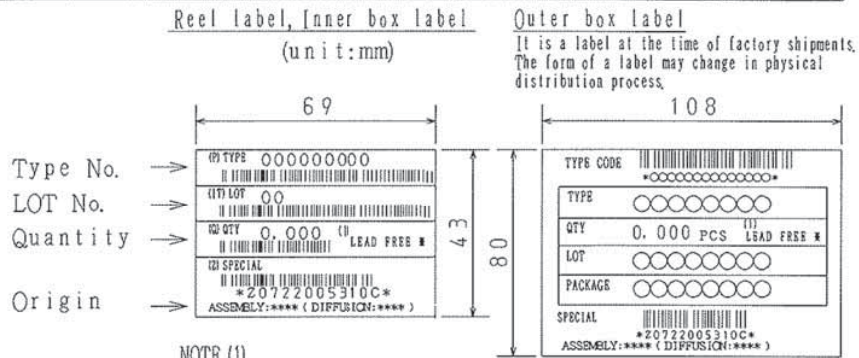
1. Packing Format

Package Name	Carrier Tape Type	Maximum Number of devices contained (pcs)			Packing format	
		Reel	Inner box	Outer box	Inner BOX (C-1)	Outer BOX (A-7)
EMH8	MCP4	3,000	15,000	90,000	5 reels contained Dimensions:mm (external) 183×72×185	6 inner boxes contained Dimensions:mm (external) 440×195×210

Packing method



Reel label



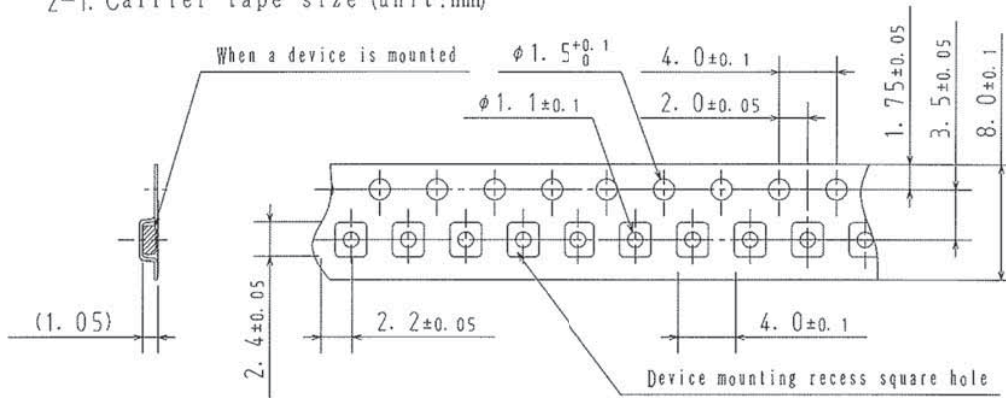
NOTE (1)

The LEAD FREE  $\times$  description shows that the surface treatment of the terminal is lead free.

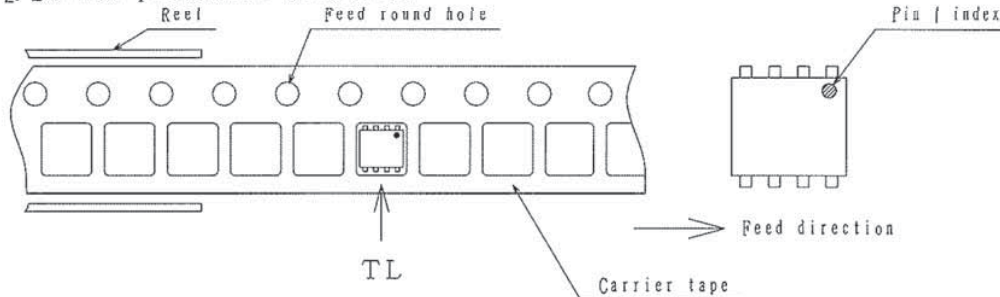
Label	JEITA Phase
LEAD FREE 3	JEITA Phase 3A
LEAD FREE 4	JEITA Phase 3

2. Taping configuration

2-1. Carrier tape size (unit:mm)



2-2. Device placement direction

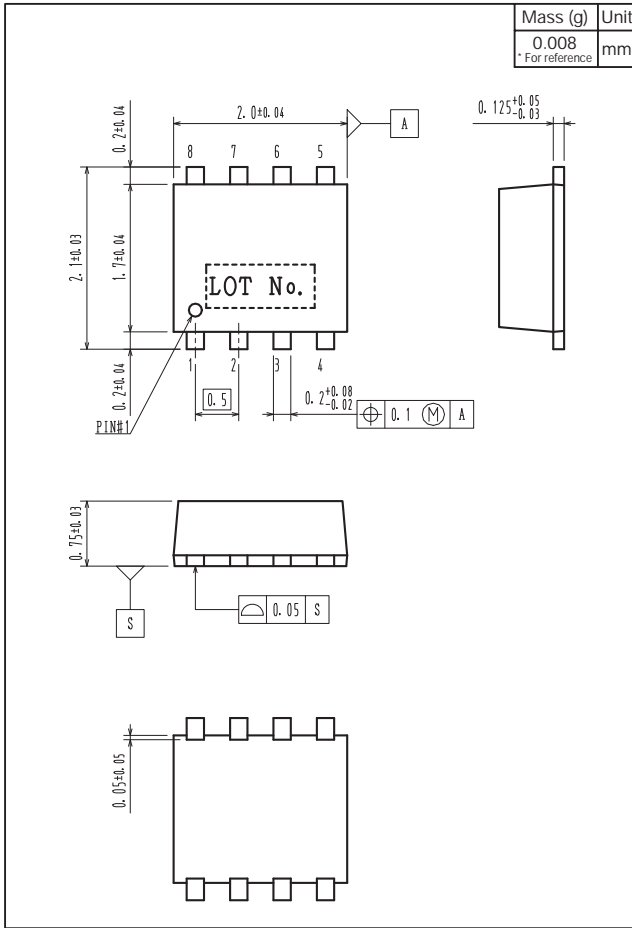


Those with pin | index on the feed hole side.....TL

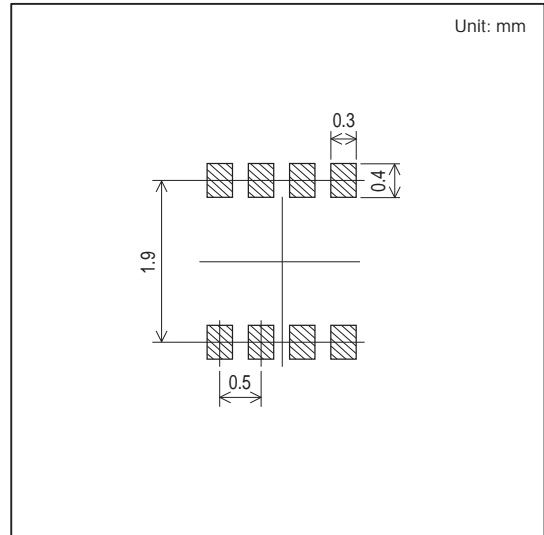
# EMH2407

## Outline Drawing

EMH2407-TL-H



## Land Pattern Example



Note on usage : Since the EMH2407 is a MOSFET product, please avoid using this device in the vicinity of highly charged objects.

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